TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type

# SSM3K122TU

Power Management Switch Applications High-Speed Switching Applications

- 1.5 V drive
- Low ON-resistance: R<sub>on</sub> = 304 mΩ (max) (@V<sub>GS</sub> = 1.5 V)
  - $R_{on}$  = 211 mΩ (max) (@V<sub>GS</sub> = 1.8 V)  $R_{on}$  = 161 mΩ (max) (@V<sub>GS</sub> = 2.5 V)
  - $R_{on} = 123 \text{ m}\Omega \text{ (max)} (@V_{GS} = 4.0 \text{ V})$

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V <sub>DSS</sub>	20	V	
Gate-Source voltage		V <sub>GSS</sub>	± 10	V	
Drain current	DC	I <sub>D</sub>	2.0	А	
	Pulse	I <sub>DP</sub>	4.0		
Drain power dissipation		PD (Note 1)	800	mW	
		PD (Note 2)	500		
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba

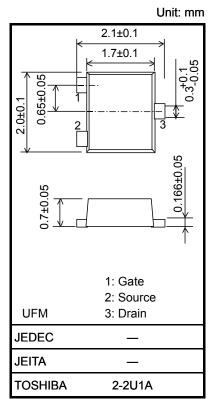
Semiconductor Reliability Handbook ("Handling Precautions"/ "Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on a ceramic board.

(25.4 mm  $\times$  25.4 mm  $\times$  0.8 t, Cu Pad: 645 mm<sup>2</sup>) Note 2: Mounted on a FR4 board.

(25.4 mm  $\times$  25.4 mm  $\times$  1.6 t, Cu Pad: 645 mm  $^2$  )

#### Electrical Characteristics (Ta = 25°C)



Weight: 6.6 mg (typ.)

Charact	eristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Drain-Source breakdown voltage	V (BR) DSS	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = 0 V		20			V	
Drain-Source Dreakdown vollage		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$	12	—	_		
Drain cutoff curren	t	IDSS	$V_{DS} = 20 V, V_{GS} = 0 V$		_		1	μA
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS}$ = ± 10 V, $V_{DS}$ = 0 V		_	—	±1	μA
Gate threshold vol	tage	V <sub>th</sub>	$V_{DS} = 3 V, I_D = 1 mA$		0.35	—	1.0	V
Forward transfer a	dmittance	Y <sub>fs</sub>	$V_{DS} = 3 V, I_D = 1.0 A$	(Note 3)	2.6	5.2	_	S
	R <sub>DS</sub> (ON)	$I_D = 1.0 \text{ A}, V_{GS} = 4.0 \text{ V}$	(Note 3)	_	87	123	mΩ	
Drain Course ON registeres		$I_D = 1.0 \text{ A}, V_{GS} = 2.5 \text{ V}$	(Note 3)	_	112	161		
Drain-Source ON-resistance		$I_D = 0.5 \text{ A}, V_{GS} = 1.8 \text{ V}$	(Note 3)	_	147	211		
		$I_D = 0.3 \text{ A}, V_{GS} = 1.5 \text{ V}$	(Note 3)		182	304		
Input capacitance		C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$		_	195	_	pF
Output capacitance		Coss			_	35	_	
Reverse transfer capacitance		C <sub>rss</sub>			_	29	_	
Total Gate Charge		Qg	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.0 A, V <sub>GS</sub> = 4 V			3.4	_	nC
Gate-Source Charge		Q <sub>gs</sub>				2.3		
Gate-Drain Charge		Q <sub>gd</sub>			_	1.1	_	
Switching time	Turn-on time	t <sub>on</sub>	V <sub>DD</sub> = 10 V, I <sub>D</sub> = 0.5 A,		_	8.0	_	
	Turn-off time	t <sub>off</sub>	$V_{GS} = 0$ to 2.5 V, $R_G = 4.7$ S	2	_	9.0	_	ns
Drain-Source forward voltage		V <sub>DSF</sub>	$I_D = -2.0 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$	(Note 3)	—	-0.85	-1.2	V

Note 3: Pulse test

Start of commercial production 2007-10

90%

lof

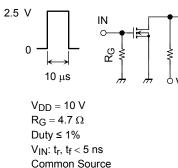
### Switching Time Test Circuit

(a) Test Circuit

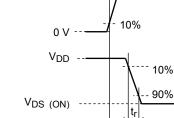
(b) V<sub>IN</sub>

(c) VOUT

OUT



Common So Ta =  $25^{\circ}$ C

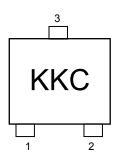


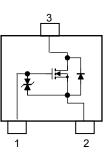
ton

2.5 V

#### Marking

#### Equivalent Circuit (top view)





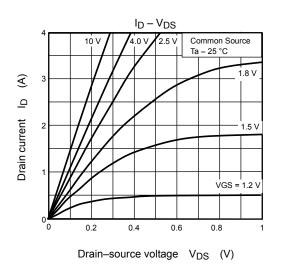
### Notice on Usage

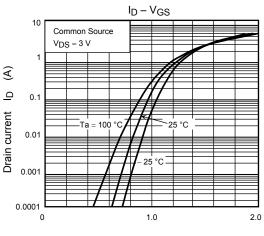
 $V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D = 1$  mA for this product. For normal switching operation,  $V_{GS}$  (on) requires a higher voltage than  $V_{th}$ , and  $V_{GS}$  (off) requires a lower voltage than  $V_{th}$ . (The relationship can be established as follows:  $V_{GS}$  (off) <  $V_{th}$  <  $V_{GS}$  (on).)

Take this into consideration when using the device.

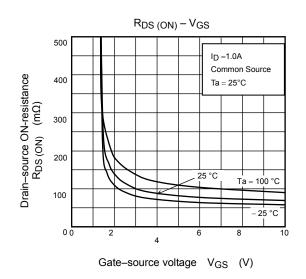
### **Handling Precaution**

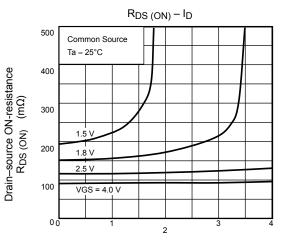
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.



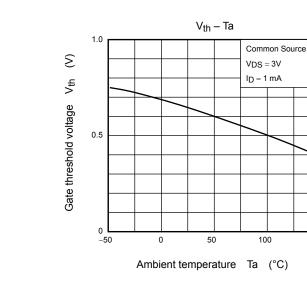


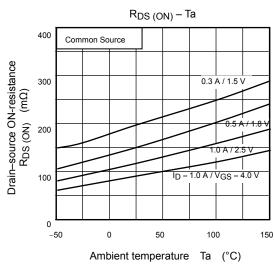
Gate-source voltage V<sub>GS</sub> (V)



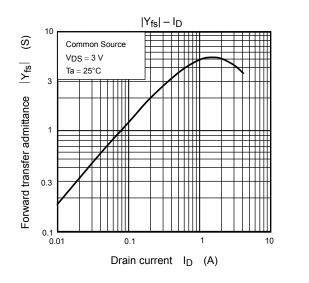


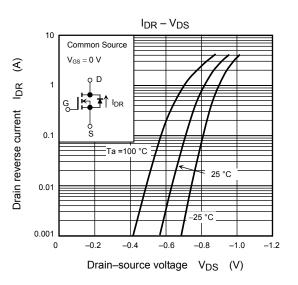
Drain current I<sub>D</sub> (A)

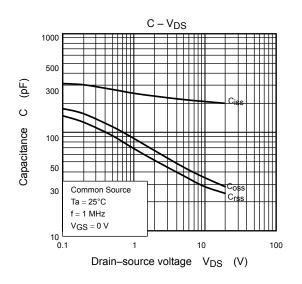


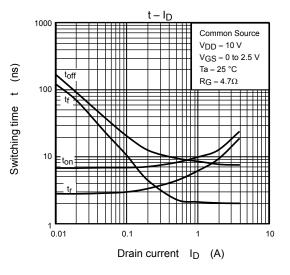


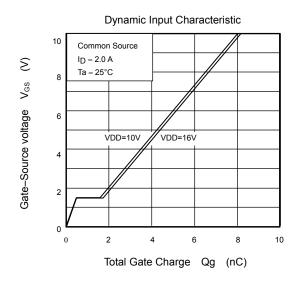
150

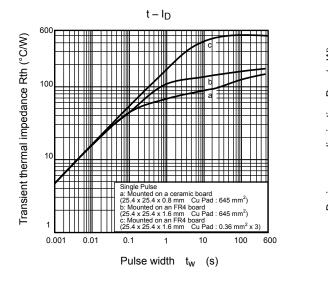


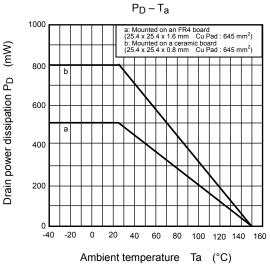












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